Ordering Information

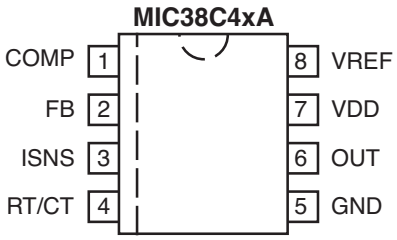
Part Number		Temperature Range	Package
Standard	Pb-Free		
MIC38C42ABM	MIC38C42AYM	–40°C to +85°C	8-pin SOIC
MIC38C43ABM	MIC38C43AYM	–40°C to +85°C	8-pin SOIC
MIC38C44ABM	MIC38C44AYM	–40°C to +85°C	8-pin SOIC
MIC38C45ABM	MIC38C45AYM	–40°C to +85°C	8-pin SOIC
MIC38C42ABMM	MIC38C42AYMM	–40°C to +85°C	8-pin MM8™
MIC38C43ABMM	MIC38C43AYMM	–40°C to +85°C	8-pin MM8™
MIC38C44ABMM	MIC38C44AYMM	–40°C to +85°C	8-pin MM8™
MIC38C45ABMM	MIC38C45AYMM	–40°C to +85°C	8-pin MM8™

Refer to the Part Number Cross Reference for a listings of Micrel devices equivalent to UC284x and UC384x devices.

Selection Guide

	UVLO Thresholds	
Duty Cycle	Startup 8.4V Minimum Operating 7.6V	Startup 14.5V Minimum Operating 9V
0% to 96%	MIC38C43A	MIC38C42A
0% to 50%	MIC38C45A	MIC38C44A

Pin Configuration



8-Lead SOIC (M)
8-Lead MM8™ (MM)

Pin Description

Pin Number	Pin Name	Pin Function
1	COMP	Compensation: Connect external compensation network to modify the error amplifier output.
2	FB	Feedback (Input): Error amplifier input. Feedback is 2.5V at desired output voltage.
3	ISNS	Current Sense (Input): Current sense comparator input. Connect to current sensing resistor or current transformer.
4	RT/CT	Timing Resistor/Timing Capacitor: Connect external RC network to select switching frequency.
5	GND	Ground: Combined analog and power ground.
6	OUT	Power Output: Totem-pole output.
7	VDD	Analog Supply (Input): Controller circuitry supply input. Return to analog ground (AGND).
8	VREF	5V Reference (Output): Connect external RC network.

Absolute Maximum Ratings

Supply Voltage (V_{DD}) 20V
Switch Supply Voltage (V_D) 20V
Current Sense Voltage (V_{ISNS}) ..... –0.3V to 5.5V
Feedback Voltage (V_{FB}) ..... –0.3V to 5.5V
Output Current (I_{OUT}) 0.5A
Storage Temperature (T_A) ..... –65°C to +150°C

Operating Ratings

Junction Temperature (T_J) ..... 150°C
Package Thermal Resistance
8-Pin MM8™ (θ_{JA}) ..... 250°C/W
8-Pin SOIC (θ_{JA}) ..... 170°C/W

Electrical Characteristics(Note 6)

V_{DD} = 15V, **Note 4**; R_T = 11.0k; C_T = 3.3nF; –40°C ≤ T_A ≤ 85°C; unless noted

Parameter	Test Conditions	Min	Typ	Max	Units
Reference Section					
Output Voltage	T_A = 25°C, I_O = 1mA	4.90	5.00	5.10	V
Line Regulation	12V ≤ V_{DD} ≤ 18V, I_O = 5µA		2	20	mV
Load Regulation	1 ≤ I_O ≤ 20mA		1	25	mV
Temp. Stability	**Note 1**		0.2		mV/°C
Total Output Variation	Line, Load, Temp., **Note 1**	4.82		5.18	V
Output Noise Voltage	10Hz ≤ f ≤ 10kHz, T_A = 25°C, **Note 1**		50		µV
Long Term Stability	T_A = 125°C, 1000 hrs., **Note 1**		5	25	mV
Output Short Circuit		–30	–80	–180	mA
Oscillator Section					
Initial Accuracy	T_A = 25°C, **Note 5**	47	53	59	kHz
Voltage Stability	12 ≤ V_{DD} ≤ 18V		0.2	1.0	%
Temp. Stability	T_{MIN} ≤ T_A ≤ T_{MAX}, **Note 1**		0.04		%/°C
Clock Ramp Reset Current	T_A = 25°C, $V_{RT/CT}$ = 2V, **Note 1**	7.7	8.4	9.0	mA
Amplitude	$V_{RT/CT}$ peak to peak		1.9		Vp-p
Error Amp Section					
Input Voltage	V_{COMP} = 2.5V	2.4	2.50	2.58	V
Input Bias Current	V_{FB} = 5.0V		–0.1	–2	µA
A_{VOL}	2 ≤ V_O ≤ 4V	65	90		dB
Unity Gain Bandwidth	**Note 1**	0.7	1.0		MHz
PSRR	12 ≤ V_{DD} ≤ 18V	60			dB
Output Sink Current	V_{FB} = 2.7V, V_{COMP} = 1.1V	2	14		mA
Output Source Current	V_{FB} = 2.3V, V_{COMP} = 5V	–0.3	–1		mA
V_{OUT} High	V_{FB} = 2.3V, R_L = 15k to ground	5	6.8		V
V_{OUT} Low	V_{FB} = 2.7V, R_L = 15k to V_{REF}		0.1	1.1	V

Parameter	Test Conditions	Min	Typ	Max	Units
Current Sense					
Gain	**Notes 2, 3**	2.85	3.0	3.15	V/V
MaximumThreshold	V_{COMP} = 5V, **Note 2**	0.9	1	1.1	V
PSRR	12 ≤ V_{DD} ≤ 18V, **Note 2**		70		dB
Input Bias Current			–0.1	–2	µA
Delay to Output			120	250	ns
Output					
$R_{DS(ON)}$ High $R_{DS(ON)}$ Low	I_{SOURCE} = 200mA I_{SINK} = 200mA		20 11		Ω Ω
Rise Time	T_A = 25°C, C_L = 1nF		40	80	ns
Fall Time	T_A = 25°C, C_L = 1nF		30	60	ns
Undervoltage Lockout					
Start Threshold	MIC38C42A/4A	13.5	14.5	15.5	V
	MIC38C43A/5A	7.8	8.4	9.0	V
Minimum Operating Voltage	MIC38C42A/4A	8	9	10	V
	MIC38C43A/5A	7.0	7.6	8.2	V
Pulse Width Modulator					
Maximum Duty Cycle	MIC38C42A/3A	94	96		%
	MIC38C44A/5A	46	50		%
Minimum Duty Cycle				0	%
Total Standby Current					
Start-Up Current	V_{DD} = 13V for MIC38C42A/44A V_{DD} = 7.5V for MIC38C43A/45A		100	230	µA
Operating Supply Current	V_{FB} = V_{ISNS} = 0V		4.0	6.0	mA

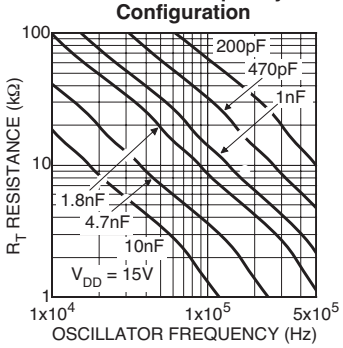
Note 1: These parameters, although guaranteed, are not 100% tested in production.
Note 2: Parameter measured at trip point of latch with V_{EA} = 0.
Note 3: Gain defined as:

$$A = \frac{\Delta V_{PIN1}}{V_{TH}(I_{SNS})}; 0 \le V_{TH}(I_{SNS}) \le 0.8V$$

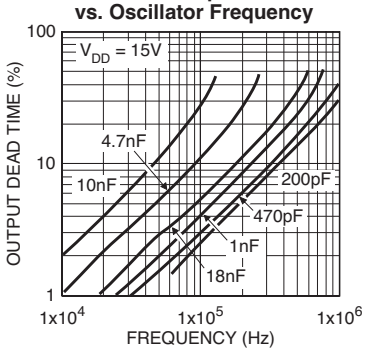
Note 4: Adjust V_{DD} above the start threshold before setting at 15V.
Note 5: Output frequency equals oscillator frequency for the MIC38C42 and MIC38C43. Output frequency for the MIC38C44A, and MIC38C45A equals one half the oscillator frequency.
Note 6: Specification for packaged product only.

Typical Characteristics

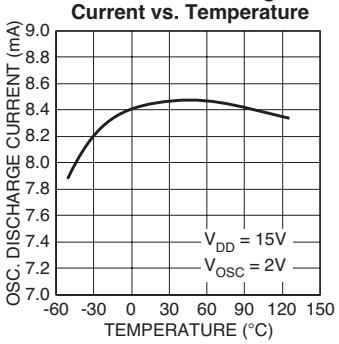
Oscillator Frequency Configuration



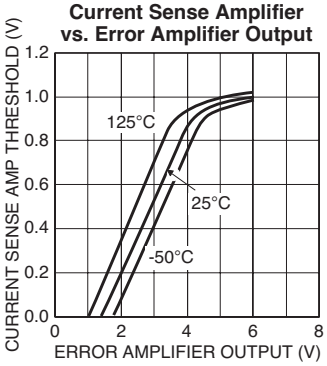
MIC38C42/43 Output Dead Time vs. Oscillator Frequency



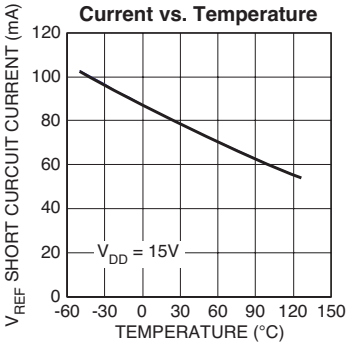
Oscillator Discharge Current vs. Temperature



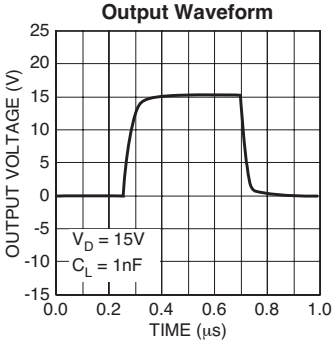
Current Sense Amplifier vs. Error Amplifier Output



Short-Circuit Reference Current vs. Temperature



MIC38C4x Output Waveform



Application Information

Familiarity with 384x converter designs is assumed.

MIC38C4x Advantages

Start-up Current

Start-up current has been reduced to an ultra-low 50μA (typical) permitting higher-valued, lower-wattage, start-up resistors (powers controller during power supply start-up). The reduced resistor wattage reduces cost and printed circuit space.

Operating Current

Operating current has been reduced to 4mA compared to 11mA for a typical bipolar controller. The controller runs cooler and the V_{DD} hold-up capacitance required during start-up may be reduced.

Output Driver

Complementary internal P- and N-channel MOSFETs produce rail-to-rail output voltages for better performance driving external power MOSFETs. The driver transistor's low on-resistance and high peak current capability can drive gate capacitances of greater than 1000pF. The value of output capacitance which can be driven is determined only by the rise/fall time requirements. Within the restrictions of output capacity and controller power dissipation, maximum switching frequency can approach 500kHz.

Design Precautions

When operating near 20V, circuit transients can easily exceed the 20V absolute maximum rating, permanently damaging the controller's CMOS construction. To reduce transients, use a 0.1μF low-ESR capacitor to next to the controller's supply V_{DD} (or V_D for '-1' versions) and ground connections. Film type capacitors, such as Wima MKS2, are recommended.

When designing high-frequency converters, avoid capacitive and inductive coupling of the switching waveform into high-impedance circuitry such as the error amplifier, oscillator, and current sense amplifier. Avoid long printed-circuit traces and component leads. Locate oscillator and compensation circuitry near the IC. Use high frequency decoupling capacitors on V_{REF}, and if necessary, on V_{DD}. Return high di/dt currents directly to their source and use large area ground planes.

Buck Converter

Refer to figure 1. When at least 26V is applied to the input, C5 is charged through R2 until the voltage V_{DD} is greater than 14.5V (the undervoltage lockout value of the MIC38C42). Output switching begins when Q1 is turned on by the gate drive transformer T1, charging the output filter capacitor C3 through L1. D5 supplies a regulated +12V to V_{DD} once the circuit is running.

Current sense transformer CT1 provides current feedback to ISNS for current-mode operation and cycle-by-cycle current limiting. This is more efficient than a high-power sense resistor and provides the required ground-referenced level shift.

When Q1 turns off, current flow continues from ground through D1 and L1 until Q1 is turned on again.

The 100V Schottky diode D1 reduces the forward voltage drop in the main current path, resulting in higher efficiency than could be accomplished using an ultra-fast-recovery diode. R1 and C2 suppress parasitic oscillations from D1.

Using a high-value inductance for L1 and a low-ESR capacitor for C3 permits small capacitance with minimum output ripple. This inductance value also improves circuit efficiency by reducing the flux swing in L1.

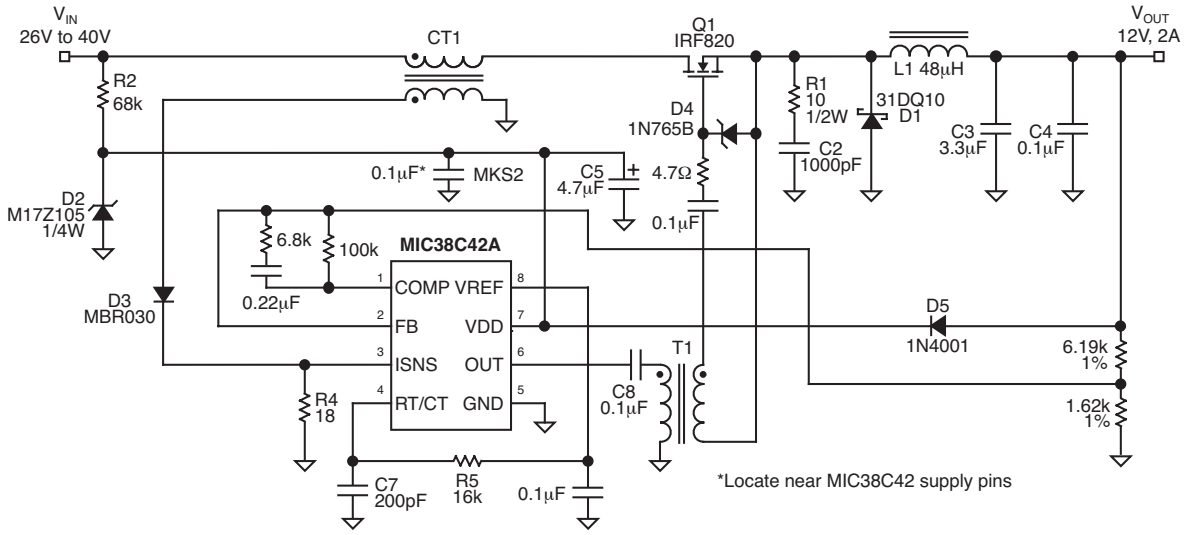


Figure 1. 500kHz, 25W, Buck Converter

Magnetic components are carefully chosen for minimal loss at 500kHz. CT1 and T1 are wound on Magnetics, Inc. P-type material toroids. L1 is wound on a Siemens N49 EFD core.

Test	Conditions	Results
Line Regulation	V_{IN} = 26V to 80V, I_O = 2A	0.5%
Load Regulation	V_{IN} = 48V, I_O = 0.2A to 2A	0.6%
Efficiency	V_{IN} = 48V, I_O = 2A	90%
Output Ripple	V_{IN} = 48V, I_O = 2A (20MHz BW)	100mV

Symbol	Custom Coil[1]	ETS[2]
CT1	4923	ETS 92420
T1	4924	ETS 92419
L1	4925	ETS 92421

1. Custom Coils, Alcester, SD tel: (605) 934-2460
2. Energy Transformation Systems, Inc. tel: (415) 324-4949.

Synchronous Buck Converter

Refer to figure 2. This MIC38C43 synchronous buck converter uses an MIC5022 half-bridge driver to alternately drive the PWM switch MOSFET (driven by GATEH, or high-side output) and a MOSFET which functions as a synchronous rectifier (driven by the GATEL, or low-side output).

The low-side MOSFET turns on when the high-side MOSFET is off, allowing current to return from ground. Current flows through the low-side MOSFET in the source to drain direction.

The on-state voltage drop of the low-side MOSFET is lower than the forward voltage drop of an equivalent Schottky rectifier. This lower voltage drop results in higher efficiency.

A sense resistor (5mΩ) is connected to the driver's high-side current sense inputs to provide overcurrent protection. Refer to the MIC5020, MIC5021, and MIC5022 data sheets for more information.

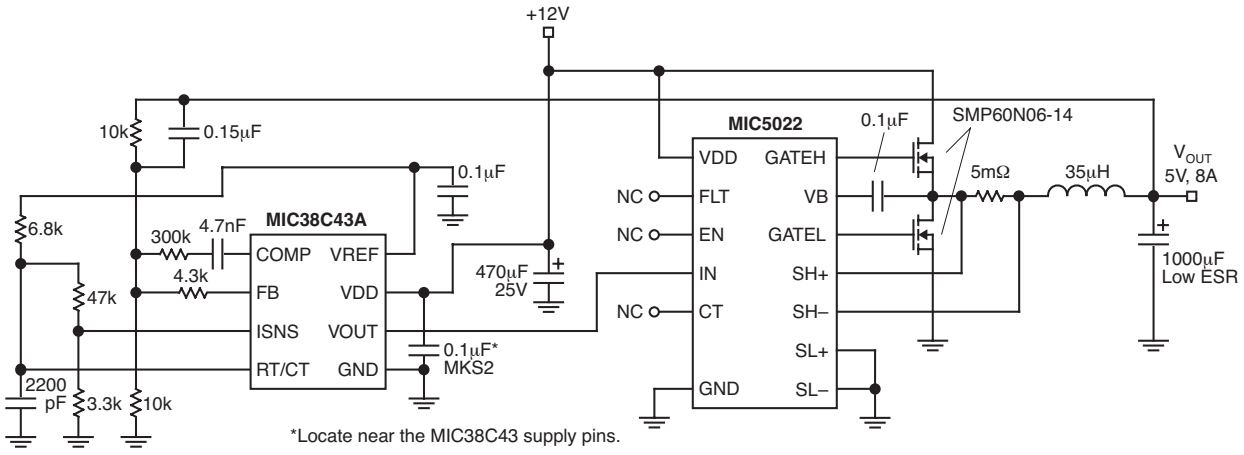
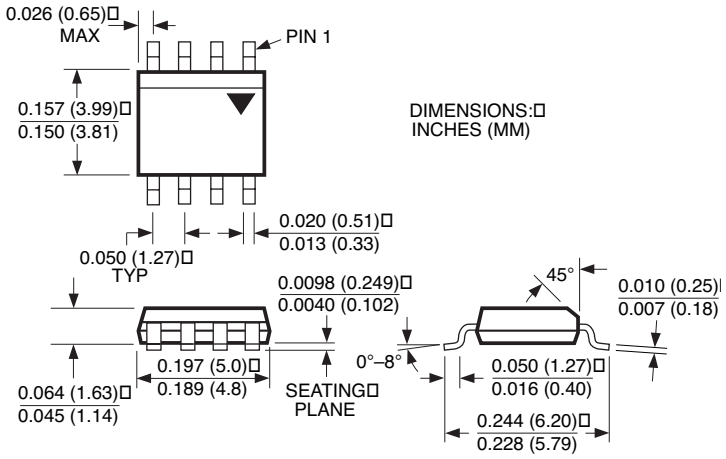
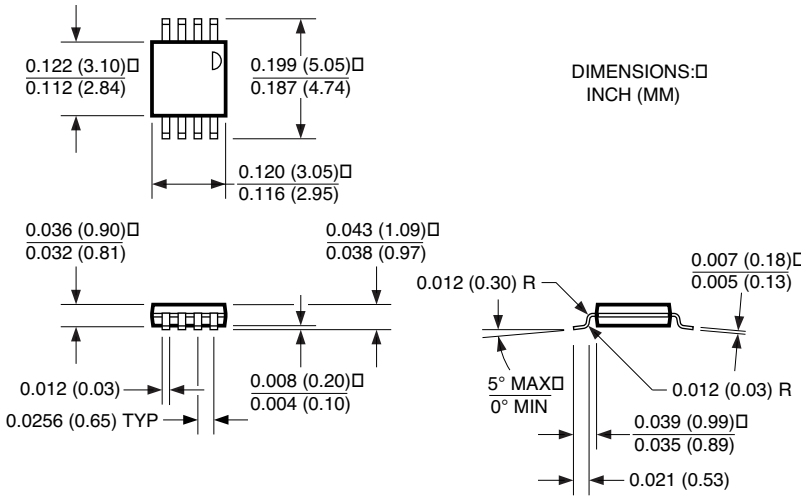


Figure 2. 100kHz, Synchronous Buck Converter

Package Information



8-Pin SOP (M)



8-Pin MSOP (MM)

MICREL INC. 2180 FORTUNE DRIVE SAN JOSE, CA 95131 USA

TEL + 1 (408) 944-0800 FAX + 1 (408) 474-1000 WEB http://www.micrel.com